## SPICE Device Model SiR826ADP



Vishay Siliconix

# N-Channel 80 V (D-S) MOSFET

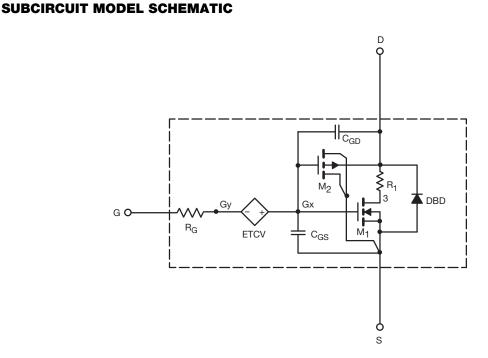
### DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge



#### Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static			•		
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	1.7	-	V
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	0.0043	0.0046	Ω
		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 15 A	0.0064	0.0062	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	71	68	S
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = 5 A	0.73	0.73	V
Dynamic <sup>b</sup>	•				
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0 V, f = 1 MHz	2840	2800	pF
Output Capacitance	C <sub>oss</sub>		1090	1100	
Reverse Transfer Capacitance	C <sub>rss</sub>		95	93	
Total Gate Charge	0	$V_{DS} = 40 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	52	57	nC
	Qg	$V_{DS}$ = 40 V, $V_{GS}$ = 4.5 V, $I_{D}$ = 20 A	25	25	
Gate-Source Charge	Q <sub>gs</sub>		8.5	8.5	
Gate-Drain Charge	Q <sub>gd</sub>		10	10	

Notes

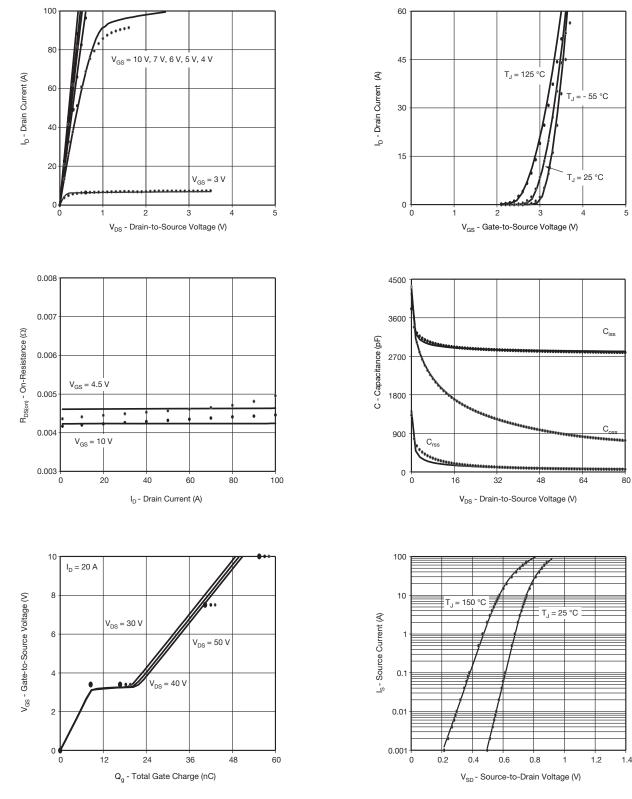
a. Pulse test; pulse width  $\leq 300~\mu\text{s},$  duty cycle  $\leq 2~\%.$ 

b. Guaranteed by design, not subject to production testing.



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### COMPARISON OF MODEL WITH MEASURED DATA (T<sub>J</sub> = 25 °C, unless otherwise noted)



### Note

• Dots and squares represent measured data.

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